# Red shift properties, crystal field theory and nephelauxetic effect on Mn<sup>4+</sup>-doped SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub> red phosphor for plant growth LED light

Simin Gu<sup>1,a,b</sup>, Mao Xia<sup>1,a,b</sup>, Cheng Zhou<sup>a</sup>, Zihui Kong<sup>a</sup>, Maxim S. Molokeev<sup>c,d</sup>, Li Liu<sup>\*,e</sup>, Wai-Yeung Wong<sup>\*,f</sup>, Zhi Zhou<sup>\*,a,b</sup>

<sup>a</sup>School of Chemistry and Materials Science, Hunan Agricultural University, Changsha, 410128, P.R. China

<sup>b</sup>Hunan Optical Agriculture Engineering Technology Research Center, Changsha, 410128, P. R. China

<sup>c</sup>Laboratory of Crystal Physics, Kirensky Institute of Physics, Federal Research Center KSC SB RAS, Krasnoyarsk 660036, Russia

<sup>d</sup>Siberian Federal University, Krasnoyarsk, 660041, Russia

<sup>e</sup>Hubei Collaborative Innovation Center for Advanced Organic Chemical Materials, Ministry of Education Key Laboratory for the Synthesis and Application of Organic Functional Molecules, School of Chemistry and Chemical Engineering, Hubei University, Wuhan 430062, China.

<sup>f</sup>Department of Applied Biology and Chemical Technology, The Hong Kong Polytechnic University, Hung Hom, Hong Kong, P. R. China.

### \*Corresponding authors:

Prof. Zhi Zhou Phone number: (+86)-13975160917; E-mail: <u>zhouzhi@hunau.edu.cn</u> Ph. D. Wai-Yeung Wong E-mail: <u>wai-yeung.wong@polyu.edu.hk</u> Ph. D. Li Liu E-mail: <u>liulihubei@hubu.edu.cn</u> <sup>1</sup> Simin Gu and Mao Xia contributed equally to this work.

### Abstract:

The discovery of novel Mn<sup>4+</sup>-doped oxide red phosphor with suitable spectrum for plant growth is a hot issue in the recent years due to the characteristic red photoluminescence of  $^2E_g \rightarrow \ ^4A_2$  transition in  $Mn^{4+}$  ions. Generally, the emission position of Mn<sup>4+</sup> is hard to tune because of specific crystal field in most phosphors. In this work, tunable luminescence property with obvious red shift in the spectra is observed in the Mn<sup>4+</sup>-doped SrMgAl<sub>10-v</sub>Ga<sub>v</sub>O<sub>17</sub> red phosphor via simple substitution of Ga<sup>3+</sup> for Al<sup>3+</sup>, and crystal field theory and nephelauxetic effect are employed to explain this phenomenon. Meanwhile, the Ga<sup>3+</sup> dopant changes the shape of the spectra because Ga<sup>3+</sup> dopant guides the replacement site of Mn<sup>4+</sup> and changes the luminescence center. Improved emission intensity is obtained because appropriate Ga<sup>3+</sup> doping leads to larger band gap and reduces non-radiative transitions. Phosphor-converted LED (pc-LED) devices fabricated with blue chip (470 nm) and the as-obtained SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphors emit bright blue and red light, which fit the absorption regions of plant pigments well, thus SrMgAl<sub>10-v</sub>Ga<sub>v</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphor can be a candidate for plant growth LED light.

**Keywords:** red shift; crystal field theory; nephelauxetic effect; SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>: Mn<sup>4+</sup>; plant growth LED light.

# 1. Introduction

Plant cultivation plays an important role in agricultural production. Conventional agriculture suffers from harsh environment such as frost, cloudy weather, droughts and rainstorms, resulting in a reduced yield, which cannot satisfy people's needs. In recent years, indoor plant cultivation (IPC) has caused a lot of concern for constructing a suitable and stable environment for plant growth. Light source is an essential condition in the growth process of all plants including branching, flowering, and fruiting [1-3]. Light energy can be converted into chemical energy by photosynthesis of plant pigments. Chlorophyll A, chlorophyll B, phytochrome P<sub>R</sub> and phytochrome PFR are four main plant pigments which mainly absorb blue (400-500 nm), red (600-700 nm) and far-red (700-780 nm) lights. The traditional light sources for indoor plant cultivation are incandescent lamps, high voltage halogen lamps and xenon lamps, which suffer from many disadvantages such as high energy consumption, short lifetime and spectral mismatch. Therefore, benefit from characteristic merits of energy saving, long lifetime, spectral match and environment friendliness, phosphor-converted light-emitting-diode (pc-LED) has gradually been widely used in IPC. As a light-conversion material, phosphors play an indispensable role in LED devices which directly determine the photoluminescence properties, so it is important to design and synthesize the phosphors with proper spectral emission and bright photoluminescence [4-6].

Based on this fact, many phosphors have been investigated and discussed to fulfil the light requirements of plant growth. Red phosphors are the ideal material for plant growth LED light because red emission is beneficial in promoting plant growth and biomass accumulation. Meanwhile, red phosphors also have wide application in white light-emitting diodes [7-10]. Nowadays, the commercial phosphor Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>:Ce<sup>3+</sup> widespread used in white LEDs is not suitable for plant growth LEDs because of the mismatched spectral bands [11, 12]. The main red phosphor  $Eu^{2+}$ -doped nitrides likes (Ca,Sr)AlSiN<sub>3</sub>: $Eu^{2+}$  [13-15] and (Ca,Sr)<sub>2</sub>Si<sub>5</sub>N<sub>8</sub>: $Eu^{2+}$  [16, 17] suffer from severe synthetic conditions with high temperature (>1800°C) and high pressure in reductive atmosphere. The critical preparation requirement increases the cost of the product and limits their large-scale use in agricultural industry. Another red phosphor is Mn<sup>4+</sup>-doped fluoride, such as K<sub>2</sub>TiF<sub>6</sub>:Mn<sup>4+</sup> [18] and K<sub>2</sub>SiF<sub>6</sub>:Mn<sup>4+</sup> [19]. Preparation of these materials often need HF while it is harmful to the environment, and they are unstable that easily decompose in moist environment because of the existence of  $[MnF_6]^{2-}$  groups. As an alternative,  $Mn^{4+}$ -doped oxides have received extensive attention for series of advantages such as attractive photoluminescence properties, high stability, low cost and eco-friendliness[20, 21]. New types of Mn<sup>4+</sup>-doped oxides such as SrLaAlO<sub>4</sub> [22], La<sub>2</sub>LiSbO<sub>6</sub> [23], Gd<sub>2</sub>ZnTiO<sub>6</sub> [24], Ca<sub>14</sub>(Ga/Al)<sub>10</sub>Zn<sub>6</sub>O<sub>35</sub> [25, 26] have been reported for plant cultivation in recent years. Mn<sup>4+</sup>-activated oxide phosphors can usually be excited by commercial blue and near ultraviolet chips because they have large photoluminescence excitation spectra ranging from 220 to 580 nm, and the emission band of these phosphors is located at

the red and far-red regions from the characteristic  ${}^{2}E_{g} \rightarrow {}^{4}A_{2}$  transitions of Mn<sup>4+</sup>. Nonetheless, the emission position of Mn<sup>4+</sup> in these matrixes is hard to tune to match the absorption of plant pigments better, so it still needs a novel matrix or method to develop red phosphors with more suitable spectrum for plant growth LED light.

Impurity doping plays a key role on the discovery of Mn<sup>4+</sup>-doped oxides as red phosphors. It can be constructed easily through the substitution between elements in one main group, because these ions usually have similar ionic radius, analogical structure and electronegativity alike. Zhao et al. [27] and Zhou et al. [28] reported that the lattice site can be adjusted by replacing  $Ga^{3+}$  with  $Al^{3+}$  in  $Ca_{14}Ga_{10-x}Al_xZn_6O_{35}$ phosphor, lead to an enhancement on photoluminescence intensity and quantum efficiency of the samples. Analogously, Qiao et al. reported a single-phase  $(Ca_{9-x}Sr_x)MgK(PO_4)_7$ : Eu<sup>2+</sup> phosphor with white light by adjusting the compositions and multiple activator sites, which show a significant shift and improvement on the photoluminescence spectra via Sr<sup>2+</sup> replace Ca<sup>2+</sup> [29]. Similar enhanced and tunable luminescence performances in Lu<sub>3-x</sub>Y<sub>x</sub>Al<sub>5</sub>O<sub>12</sub>:Mn<sup>4+</sup> red phosphor can also be explained in details due to the substitution of  $Y^{3+}$  for Lu<sup>3+</sup> [30]. Taking the inspiration from these literatures, we assumed  $Ga^{3+}$  to replace  $Al^{3+}$  in  $SrMgAl_{10}O_{17}$ :Mn<sup>4+</sup> phosphor to improve luminescence properties. As far as we know, no similar literature has been reported.

In this study, a novel Mn<sup>4+</sup>-doped SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub> red phosphor with tunable and improved luminescence properties is discovered. The samples were prepared through high-temperature solid-state method in atmospheric environment. The phase structure, photoluminescence (PL) and photoluminescence excitation (PLE) spectra, absorption spectra, quantum efficiency, lifetime decay curves and electroluminescence properties are investigated in detail. Finally, series of LED devices combined with blue chips and the as-obtained phosphors show bright blue and red emissions which match the plant absorption spectrum well, indicates this phosphor can be a candidate for indoor plant growth light.

### 2. Experimental section

The raw materials were SrCO<sub>3</sub> (99.99%), MgO (99.99%), Al<sub>2</sub>O<sub>3</sub> (99.99%), Ga<sub>2</sub>O<sub>3</sub> (99.99%) and MnCO<sub>3</sub> (99.99%), which were bought from Aladdin without further purification. Different contents of H<sub>3</sub>BO<sub>3</sub> (AR) (1, 2, 3, 4, 5% wt) acted as flux in the reaction process. All reagents were weighed following the stoichiometric ratio and put into an agate mortar, dropped with a certain amount of absolute ethyl alcohol. These powders were ground for 30 minutes to mix up uniformly then transferred into corundum crucibles. They were put into a tube furnace preheated at 800 °C for 2 hours and sintered at 1500 °C in ambient atmosphere for 5 hours with a heating rate of 5 °C/min in the whole process. All samples were cooled down to room temperature naturally and then reground to fine powders. Finally, the SrMgAl<sub>10</sub>O<sub>17</sub>:xMn<sup>4+</sup> (x = 0.1%, 0.3%, 0.5%, 1.0%, 1.5%, 2.0%) and SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> (y = 1, 2, 3, 4, 5, 6) samples were obtained.

The X-ray powder diffraction (XRD) patterns were measured ranging from  $10^{\circ}$  to  $80^{\circ}$  by a diffractometer (D/SHIMADZU-6000, Japan) which equipped with Cu-Ka radiation ( $\lambda$ =1.5406 Å). The scanning rate was 6°/min and operating voltage and

current were 40 kV and 40 mA. F-4700 fluorescence spectrophotometer (Hitachi, Japan) was used to obtain the photoluminescence excitation (PLE) and photoluminescence (PL) spectra with a 150W Xe lamp as the excitation lamp. The UV-vis absorption spectra were tested on U-3310 spectrophotometer (Hitachi, Japan). Temperature-dependent PL spectra were measured using F-7000 Spectro-photometer (Hitachi, Japan) by changing the testing temperature from 298 K to 473 K. FLS 1000 fluorescence spectrometer (Edinburgh, UK) was used to get the lifetime curves and quantum efficiency. The photographs of sample were taken by Sony A6400 camera.

The LED devices were fabricated using two-component epoxy resin (Kraft K-9761) to encapsulate the as-obtained phosphors on the blue chip. The transparent resin A and B was mixed with the weight rate of 2:1, then the well-mixed resin and phosphor further mixed with the weight ration changed from 1:1 to 1:3. An ATA-500 measurement system (Everfine, China) was used to carry out the luminescence spectra of these LED devices.

### 3. Results and discussion

#### 3.1. Structure and phase characterization

First of all, H<sub>3</sub>BO<sub>3</sub> was chosen as flux in the synthesis process, as shown in Fig.S1 (a). The XRD pattern of samples exhibit impurity phase of SrAl<sub>2</sub>O<sub>4</sub> before the content of H<sub>3</sub>BO<sub>3</sub> is below 2 wt %, and after that the XRD represent pure phase of SrMgAl<sub>10</sub>O<sub>17</sub> with the standard card of PDF#26-0879. Considering the photoluminescence excitation (PLE) and emission (PL) spectra of samples with different content of flux, the emission intensity come to the maximum when 2 wt %

H<sub>3</sub>BO<sub>3</sub> participate in the synthesis reaction, and thus this condition is selected in the following section.

The SrMgAl<sub>10</sub>O<sub>17</sub> crystal belongs to P63/mmc space group with hexagonal structure as shown in Fig.1 (a). It is worth noting that the asymmetric part of the unit cell contains four independent sites of Al<sup>3+</sup> which can be written as two [AlO<sub>6</sub>] and two [AlO<sub>4</sub>]. One type of  $Al^{3+}$  in tetrahedron [AlO<sub>4</sub>] shares the position with  $Mg^{2+}$ randomly. In general, activator ion Mn<sup>4+</sup> prefers to replace Al<sup>3+</sup> in octahedron [AlO<sub>6</sub>] position due to the similar ionic radius between  $Mn^{4+}$  (r = 0.530 Å, CN = 6) and  $Al^{3+}$ (r = 0.535 Å, CN = 6), and  $\text{Mn}^{4+}$  is more stable in octahedral environment with stronger ligand-field stabilization energy [31]. When a small quantity of  $Mn^{4+}$  replace  $Al^{3+}$  in the SrMgAl<sub>10</sub>O<sub>17</sub> matrix, the XRD patterns keep the original position without any shift, the experimental results are shown in Fig. S2. Rietveld refinement analysis is performed in SrMgAl<sub>10</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> sample, and there are still two impurities phase SrAl<sub>2</sub>O<sub>4</sub> and MgAl<sub>2</sub>O<sub>4</sub>, the contents of them are determined to be 6.38% and 7.50%. The cell parameters of this sample are listed as a = b = 5.62 Å, c = 22.41 Å and V = 614.25 Å<sup>3</sup>, while these parameters in pure SrMgAl<sub>10</sub>O<sub>17</sub> are a = b = 5.63 Å, c = 22.47 Å and V = 616.80 Å<sup>3</sup>, indicates that Mn<sup>4+</sup> is doped into the unit cell successfully. With more Ga<sup>3+</sup> doped into the phosphor, the XRD curves exhibit complex phase gradually, as seen in Fig.1 (b). The sample y = 0 match well with the standard card of SrMgAl<sub>10</sub>O<sub>17</sub> at first, then MgAl<sub>2</sub>O<sub>4</sub> appear and its content gradually increase. XRD pattern of the sample y = 3 shows two phases: SrMgAl<sub>10</sub>O<sub>17</sub> and MgAl<sub>2</sub>O<sub>4</sub>, which are noted as  $\bullet$  and  $\blacklozenge$  respectively. According to literature research,

there is no report about Mn<sup>4+</sup> luminescence property in single MgAl<sub>2</sub>O<sub>4</sub> matrix. Wu et al [32] found that MgAl<sub>2</sub>O<sub>4</sub>:Mn<sup>4+</sup> sample show no photoluminescence emission but MgAl<sub>2</sub>O<sub>4</sub> phase have advantages on the luminescence performance of the MgAl<sub>2</sub>O<sub>4</sub>/CaAl<sub>12</sub>O<sub>19</sub>:Mn<sup>4+</sup> composite sample. Accordingly, combined with the experiment results, it can expect that a small amount of MgAl<sub>2</sub>O<sub>4</sub> phase can enhance the luminescence properties of sample. With further increasing of Ga<sup>3+</sup> dopant, the phase of samples are mainly composed of SrMgAl<sub>10</sub>O<sub>17</sub> host, XAl<sub>2</sub>O<sub>4</sub> (X=Mg<sup>2+</sup>, Mn<sup>2+</sup>) and Ga<sub>2</sub>O<sub>3</sub>, and it should be noticed that the latter three compounds have similar XRD pattern with almost the same peak position. Considering there is no octahedral coordination in these phases as suitable luminescence centers for Mn<sup>4+</sup>, thus they have little effect on the luminescence properties of sample theoretically.

# 3.2. Photoluminescence properties of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>4</sub>:xMn<sup>4+</sup> phosphors

Fig. 2(a) and (c) exhibit the PLE ( $\lambda_{em} = 662 \text{ nm}$ ) and PL ( $\lambda_{ex} = 320 \text{ nm}$  and  $\lambda_{ex} = 467 \text{ nm}$ ) spectra of SrMgAl<sub>10</sub>O<sub>17</sub>:xMn<sup>4+</sup> phosphors. It is obvious that the excitation and emission intensities are increasing with a rising concentration of Mn<sup>4+</sup> at first, both of them reach maximum when x = 1.0% and then decrease with more Mn<sup>4+</sup> doping. For the purpose of researching the concentration quenching behavior of SrMgAl<sub>10</sub>O<sub>17</sub>:xMn<sup>4+</sup> phosphor, the critical distance  $R_c$  is taken into account, whose value can be determined by the equation below [33, 34]:

$$R_c \approx 2 \left[ \frac{3V}{4\pi x_c N} \right]^{1/3} \tag{1}$$

where V stands for the cell volume,  $x_c$  is the critical concentration of Mn<sup>4+</sup> and N refers to the number of available sites occupied by Mn<sup>4+</sup>, respectively. For

SrMgAl<sub>10</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphor, V = 614.25 Å<sup>3</sup>,  $x_c = 0.010$  and N = 2, and the  $R_c$  is calculated to be 38.86 Å. This value is much larger than 5 Å which corresponding to the interaction between activator ions, therefore, the concentration quenching of SrMgAl<sub>10</sub>O<sub>17</sub>:xMn<sup>4+</sup> belongs to the multipolar-multipolar interaction which can be divided to be dipole–dipole (d–d), dipole–quadrupole (d–q), and quadrupole–quadrupole (q–q) interactions, respectively. They refer to different values of  $\theta$  in the following formula, which is often used to reflect the interactions based on the Dexter's theory [35, 36]:

$$\frac{l}{x} = k \left[ 1 + \beta(x)^{\theta/3} \right]^{-1}$$
(2)

where *I* and *x* mean the emission intensity and concentration of  $Mn^{4+}$  dopant, *k* and  $\beta$  refer to a certain excitation condition and specific matrix crystal, and  $\theta = 6$ , 8, 10 refer to d–d, d–q, and q–q interactions, respectively.

The specific value of  $\theta$  is usually obtained by the slope of the dependence of  $\log(I/x)$  versus log (x). From the inset in Fig. 2(a), there are two fitting lines corresponding to 320 nm and 467 nm for the excitation wavelength, two slopes are -1.029 and -1.046, respectively. The  $\theta_1$  and  $\theta_2$  are calculated to be 3.087 and 3.138, respectively, both of them are close to 6 which indicate the concentration quenching mechanism is dipole–dipole (d–d) interaction in SrMgAl<sub>10</sub>O<sub>17</sub>:xMn<sup>4+</sup> phosphor.

According to Fig.2 (b), the PLE spectrum of SrMgAl<sub>10</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> is fitted into three Gaussian peaks located at 32468, 27472 and 22026 cm<sup>-1</sup>, they are related to  ${}^{4}A_{2} \rightarrow {}^{4}T_{1}$ ,  ${}^{4}A_{2} \rightarrow {}^{2}T_{2}$  and  ${}^{4}A_{2} \rightarrow {}^{4}T_{2}$  transitions of Mn<sup>4+</sup>, respectively. The PLE spectra of SrMgAl<sub>10</sub>O<sub>17</sub>:xMn<sup>4+</sup> phosphors have a large range from 220 to 580 nm, indicates that these phosphors can be easily excited by commercial blue and near-UV chips. Fig. 3(a) and (b) exhibit the photoluminescence excitation (PLE) and photoluminescence (PL) spectra of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> samples. The intensity of PLE and PL spectra both increase with an incremental content of Ga<sup>3+</sup> doping, and come to the maximum when y = 3. It is worth noting that the shape of PL spectrum changed significantly upon Ga<sup>3+</sup> doping which related to a shift of the luminescence center. In the sample of SrMgAl<sub>10</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> (y = 0), the emission come from the Al center absolutely. When Ga<sup>3+</sup> replace Al<sup>3+</sup> in samples from y = 1 to y = 6, new luminescence center of Ga site is generated, thus resulted in the change of spectra. Another interesting phenomenon is that the normalized PLE spectra exhibit obvious red shift as shown in Fig.3 (c), that the <sup>4</sup>A<sub>2</sub>→<sup>2</sup>T<sub>2</sub> transitions show a great enhancement and red shift with the increase of Ga<sup>3+</sup> doping. Meanwhile, PL spectra excited at different wavelength all show slight red shift in Fig. 3 (d) and Fig. S4.

Based on this situation, crystal field theory and nephelauxetic effect are employed to explain these phenomena. There are three parameters to assess the effect of crystal field on the luminescent properties of  $Mn^{4+}$  that are described as the crystal-field parameter ( $D_q$ ), Racah parameters (B) and (C), respectively. They are directly related to the PLE and PL spectra, and the values of  $D_q$ , B and C can be calculated from following equations [30, 37]:

$$D_q = \frac{E({}^{4}A_2 - {}^{4}T_2)}{10} \quad (3)$$
$$\frac{D_q}{B} = \frac{15(x-8)}{(x^2 - 10x)} \quad (4)$$
$$x = \frac{E({}^{4}A_2 - {}^{4}T_1) - E({}^{4}A_2 - {}^{4}T_2)}{D_q} \quad (5)$$

$$\frac{E({}^{2}E_{g}-{}^{4}A_{2})}{B} = \frac{3.05C}{B} + 7.9 - \frac{1.8B}{D_{q}} \quad (6)$$

According to Fig. 2, the energy levels of  ${}^{4}T_{1}$ ,  ${}^{4}T_{2}$  and  ${}^{2}E_{g}$  in SrMgAl<sub>10</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> are 32468, 22026 and 15110 cm<sup>-1</sup>, and its  $D_{q}$ , B and C are calculated to be 2203, 1123 and 2423 cm<sup>-1</sup>, respectively. The value of  $D_{q}/B$  is evaluated to be 2.1, means that Mn<sup>4+</sup> is exposed in a weak crystal field in SrMgAl<sub>10</sub>O<sub>17</sub> matrix. Meanwhile, with the concentration of Ga<sup>3+</sup> dopant increasing from 10% to 60%, the values of  $D_{q}/B$  are determined to be 2.22, 2.23, 2.24, 2.35, 2.43 and 2.49 which reveal a strong crystal field [38]. However, the change of crystal field is not the main reason in the red shift of Mn<sup>4+</sup> emission due to its characteristic parity-forbidden d-d transition, and the nephelauxetic effect takes the predominant role in the luminescence of Mn<sup>4+</sup> in most oxide phosphors[39, 40]. The nephelauxetic effect has an influence on the energy of parity-forbidden  ${}^{2}E_{g} \rightarrow {}^{4}A_{2}$  transition of Mn<sup>4+</sup>, which can be described by the following formula [41, 42]:

$$\beta_1 = \sqrt{(\frac{B}{B_0})^2 + (\frac{C}{C_0})^2}$$
 (7)

where  $B_0$  and  $C_0$  are the Racah parameters for free ions, and the values of them are  $B_0$ = 1160 cm<sup>-1</sup> and  $C_0$  = 4303 cm<sup>-1</sup> for Mn<sup>4+</sup>, respectively. The details of these parameters about crystal field and nephelauxetic effect of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphors are listed in Table 1.

According to the Tanabe-Sugano energy-level diagram of  $Mn^{4+}$  as shown in Fig. 4, the energy of  ${}^{2}E_{g} \rightarrow {}^{4}A_{2}$  transition of  $Mn^{4+}$  is mainly determined by the Racah parameter *B* which relates to chemical bonding between the  $Mn^{4+}$  and the ligand. In general, a weaken nephelauxetic effect in bonding has smaller Racah parameter B, and thus shift down energy scale of <sup>2</sup>E level [43, 44], means it has lower energy. Meanwhile, wavelength is inversely proportional to energy that can ascribe to  $\lambda$ =1240/E, thus lower energy E results in longer wavelength, corresponding to red-shift phenomenon of the emission position. To sum up, a smaller value of the Racah parameter *B* gives the lower energy of <sup>2</sup>E<sub>g</sub> $\rightarrow$ <sup>4</sup>A<sub>2</sub> transition, corresponding to the red-shift phenomenon in the luminescence emission, and experimental results are in agreement with the theory.

Fig. 5(a) shows the diffuse reflection spectra of these powder samples, it is obvious that the reflection rate are decreasing with more content of Ga<sup>3+</sup>, which has the same trend as a change of the PLE spectra. All diffuse reflection curves can be divided into four parts corresponding to the absorption of matrix and  ${}^{4}A_{2}\rightarrow {}^{4}T_{1}$ ,  ${}^{4}A_{2}\rightarrow {}^{2}T_{2}$ ,  ${}^{4}A_{2}\rightarrow {}^{4}T_{2}$  transitions of Mn<sup>4+</sup>, respectively, which is consistent with the Gaussian fitting of PLE spectrum mentioned above. The diffuse reflection spectra can be translated into UV-vis absorption spectra, and get the band gap energy further through the following equation [45, 46]:

$$(\alpha hv)^{1/2} = A \left( hv - E_g \right) \quad (8)$$

where  $\alpha$  and A stand for the absorption parameter and proportional constant, hv and  $E_g$  refer to the photon energy and the band gap, respectively. The band gap energy of this series samples increases from 5.25 eV to 5.44 eV and then drops down to 5.21 eV, as shown in Fig.5 (b).

For the purpose of investigating the luminescence kinetics in SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphors, the lifetime of these samples are measured and

displayed in Fig.6 (a). All of these curves fit well with the double-exponential decay model, see the following formula [47]:

$$I(t) = I_0 + C_1 \exp(-t/\tau_1) + C_2 \exp(-t/\tau_2)$$
(9)

And the average lifetime  $\tau_{\text{ave.}}$  can be further calculated as [48]:

$$\tau_{\text{ave.}} = \frac{C_1 \tau_1^2 + C_2 \tau_2^2}{C_1 \tau_1 + C_2 \tau_2} \tag{10}$$

where *I* and *I*<sub>0</sub> stand for the photoluminescence intensity at time t and 0, *C*<sub>1</sub> and *C*<sub>2</sub> refer to pre-exponential factors,  $\tau_1$  and  $\tau_2$  are the lifetime components, respectively. The average lifetimes of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:Mn<sup>4+</sup> are calculated to be 0.446, 0.476, 0.383, 0.320, 0.266, 0.207 and 0.126 ms when the Ga<sup>3+</sup> dopant increased from 0 to 60%. Details about fitting information of the decay times are shown in the Table S1. The double-exponential decay model indicates that Mn<sup>4+</sup> should have two luminescence centers in SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub> matrix, which is consistent with the emission spectra.

Quantum efficiency (QE) is an important parameter to evaluate luminescence property of phosphors, the internal quantum efficiency (IQE) of SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> and SrMgAl<sub>10</sub>O<sub>17</sub>:Mn<sup>4+</sup> samples are shown in Fig.6 (b) and Fig.S5, which can be calculated via the following formula [49, 50]:

$$\eta = \frac{\int L_S}{\int E_R - \int E_S} \tag{11}$$

herein,  $\eta$  is internal quantum efficiency,  $L_S$  stands for the luminescence spectra of the sample,  $E_R$  and  $E_S$  refer to the excitation line of BaSO<sub>4</sub> reference and sample, respectively. The IQE of SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> and SrMgAl<sub>10</sub>O<sub>17</sub>:Mn<sup>4+</sup> are determined to be 29.67% and 51.40%. These values of the samples are at a moderate

level compared to other red or deep red phosphors that have been reported such as  $SrLaScO_4:Mn^{4+}$  (IQE: 12.2%) [51], NaGdCa<sub>4</sub>W<sub>2</sub>O<sub>12</sub>:Mn<sup>4+</sup> (IQE: 21.0%) [52],  $SrAl_3BO_7:Mn^{4+}$  (IQE: 26.0%) [53], Ba<sub>2</sub>YNbO<sub>6</sub>:Mn<sup>4+</sup> (IQE: 29.2%) [54], Ca<sub>2</sub>LaSbO<sub>6</sub>:Mn<sup>4+</sup> (IQE: 52.2%) [55]. Nevertheless, the photoluminescence properties of  $SrMgAl_{10-y}Ga_yO_{17}:Mn^{4+}$  phosphors are expected to improve via further modification process likes charge compensation or energy transfer with co-doping sensitizer ion.

Fig.7 (a) and (b) are the temperature-dependence luminescence spectra to evaluate the thermal stability of phosphor. The emission intensity decreases rapidly as the temperature increasing in both of the two samples, and the decline trend is more serious in SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphor. It because that Ga<sup>3+</sup> doping destroys the stability of matrix structure to some extent and leads to lower activation energy, promotes the loss of energy with non-radiative processes and results in worse thermal stability. Therefore, thermal stability of this phosphor needs to be further improved through modifications such as coating and synthesis optimization to fit further applications.

Fig. 8 shows the mechanism diagram in SrMgAl<sub>9</sub>GaO<sub>17</sub>:Mn<sup>4+</sup> and SrMgAl<sub>4</sub>Ga<sub>6</sub>O<sub>17</sub>:Mn<sup>4+</sup> for clearly describing the energy transition process. There is only Mn<sup>4+</sup> ion transition emission in these phosphors, electron is excited from  ${}^{4}A_{2}$  energy level to  ${}^{4}T_{1}$ ,  ${}^{4}T_{2}$  and even conduction band, and then relaxes to  ${}^{2}E_{g}$  level through non-radiative transition process, finally transfers to  ${}^{4}A_{2}$  level with bright red emission. According to the results calculated above, the sample with more Ga<sup>3+</sup>

dopant has lower energy in the  ${}^{4}T_{1}$ ,  ${}^{4}T_{2}$  and  ${}^{2}E_{g}$  states, and the energy of  ${}^{2}E_{g} \rightarrow {}^{4}A_{2}$ transition directly decide the position of red emission. Therefore, there is an obvious red shift on the PLE and PL spectra with more content of Ga<sup>3+</sup> in SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphors.

### 3.3. The emission property of as-obtained LED device

In order to search for the potential application of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphor, LED devices are fabricated with 470 nm blue chips and different content of the as-obtained SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> sample, the emission spectra are shown in Fig.9 (a) and (b). The red emission continues rising with an increasing content of phosphor, indicates that the ratio of blue and red light can be easily adjusted to meet the needs of different plants growth. The CIE chromaticity coordinates of these device change from (0.1456, 0.0365) to (0.5776, 0.2291), that from blue light to red light. Other four chromaticity coordinates with different content of the phosphor are (0.1852, 0.0603), (0.2149, 0.0754), (0.3391, 0.1256), and (0.4578, 0.1782), respectively. The emission spectrum of the fabricated LED device with appropriate phosphor is mainly composed of the blue band (420-500 nm) and red band (650-750 nm) with the peak at 470 nm and 663 nm, which can fit the absorption spectra of plant pigment including chlorophyll *A*, B and phytochrome P<sub>R</sub>, P<sub>FR</sub>, indicates that the SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphors can be a candidate for plant growth LED light.

### 4. Conclusions

In this work, a series of novel SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:xMn<sup>4+</sup> red phosphors with enhanced and tunable luminescence properties were synthesized through high

temperature approach. An appropriate amount of Ga<sup>3+</sup> dopant improves the luminescent intensity to 163% in SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> sample compared to the original SrMgAl<sub>10</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphor and causes the red shift in photoluminescence excitation (PLE) and photoluminescence (PL) spectra. The red shift observed in the spectra is explained by crystal field theory and nephelauxetic effect. All samples have a broad band in the PLE spectra ranging from 220 to 580 nm indicates they can be excited by both near ultraviolet and blue chips. The Ga<sup>3+</sup> dopant increases the band gap of SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> sample to reduce non-radiative transitions and improve the emission intensity but leads to worse thermal stability for its low activation energy. Devices assembled with blue chip and the as-obtained SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphor emits bright blue and red light which match the plant absorption spectra well, thus the SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:Mn<sup>4+</sup> phosphor have potential application on plant growth LED light.

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### Appendix A. Supplementary data

Supplementary data to this article can be found online at https://www.sciencedirect.com/

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Sample	${}^{4}A_{2} \rightarrow {}^{4}T_{1}$ (cm <sup>-1</sup> )	$^{4}A_{2} \rightarrow ^{4}T_{2}$ (cm <sup>-1</sup> )	$^{2}E_{g}\rightarrow ^{4}A_{2}$ (cm <sup>-1</sup> )	$D_q$	В	С	D <sub>q</sub> /B	$\beta_1$
y=0	32468	22026	15110	2203	1123	2423	1.96	1.120
y=1	30303	21097	15133	2110	951	2797	2.22	1.046
y=2	29940	20877	15129	2088	935	2833	2.23	1.040
y=3	29674	20704	15115	2070	924	2852	2.24	1.036
y=4	29240	20619	15106	2062	876	2952	2.35	1.020
y=5	28986	20576	15088	2058	847	3008	2.43	1.011
y=6	28653	20450	15047	2045	821	3051	2.49	1.002

**Table 1** Energy States, crystal field parameters and calculated values of  $\beta_1$  inSrMgAl10-yGayO17:1.0%Mn4+ (y=0, 1, 2, 3, 4, 5, 6) phosphors.

### **Figures Captions**

**Fig.1.** (a) The crystal structure of  $SrMgAl_{10}O_{17}$  host, the coordination environment of the octahedron [AlO<sub>6</sub>] and tetrahedron [AlO<sub>4</sub>]; (b) The XRD patterns of  $SrMgAl_{10-y}Ga_yO_{17}$ :1.0%Mn<sup>4+</sup> (y = 0, 1, 2, 3, 4, 5, 6) phosphors.

**Fig.2.** (a) The photoluminescence excitation (PLE) spectra of  $SrMgAl_{10}O_{17}:xMn^{4+}$  (x=0.1%, 0.3%, 0.5%, 1.0%, 1.5%, 2.0%), and the inset is the dependence of log(I/x) versus log(x); (b) Gaussian fitting of  $SrMgAl_{10}O_{17}:1.0\%Mn^{4+}$  sample; (c) The photoluminescence (PL) spectra of samples under the excitation of 320 nm and 467 nm respectively, and the inset is the tendency of emission intensity varies with  $Mn^{4+}$  doping concentration.

**Fig.3.** (a) Photoluminescence excitation and (b) photoluminescence spectra of  $SrMgAl_{10-y}Ga_yO_{17}:1.0\%Mn^{4+}$  (y=0, 1, 2, 3, 4, 5, 6) phosphors; the normalized PLE spectra (c) monitored at 663 nm; the normalized PL spectra under (d) 340 nm excitation, and the insets are enlarged part of the peaks in the wavelength ranging from 658 to 668 nm.

Fig.4. Tanabe-Sugano energy-level diagram of Mn<sup>4+</sup> in SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphors.
Fig.5. (a) The diffuse reflection spectra of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphors and one PLE spectrum of SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> sample; (b) the corresponding band gap energy fitting.
Fig.6. (a) The lifetime decay curves of SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphors monitored at 661

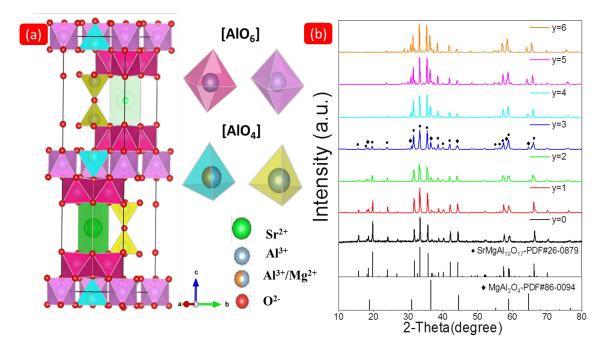
nm; the measurement of quantum efficiency of (b) SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup>, and the insets are the enlarged pattern ranging from 600 nm to 780 nm.

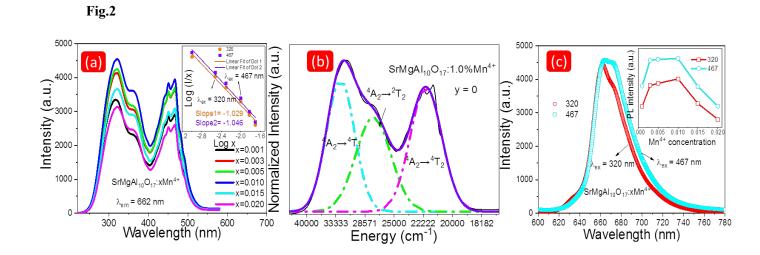
**Fig.7.** The temperature-dependence luminescence spectrum of (a) SrMgAl<sub>10</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> and (b) SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup>; (c) configurational coordinate diagram for Mn<sup>4+</sup> ions in SrMgAl<sub>10-y</sub>Ga<sub>y</sub>O<sub>17</sub> phosphor.

**Fig.8.** Mechanism diagram of luminescence in SrMgAl<sub>9</sub>GaO<sub>17</sub>:1.0%Mn<sup>4+</sup> and SrMgAl<sub>4</sub>Ga<sub>6</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> phosphors.

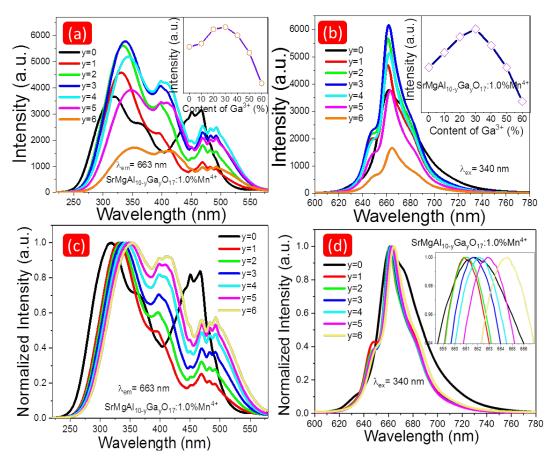
Fig.9. (a) (b) Emission spectra of the fabricated LEDs combined with 470 nm blue chip and different contents of SrMgAl<sub>7</sub>Ga<sub>3</sub>O<sub>17</sub>:1.0%Mn<sup>4+</sup> sample, and the insets are the photos of the device; (c) CIE chromaticity diagram of LED devices; (d) the comprehensive comparison between emission spectra of device and the absorption curves of the plant pigments of Chlorophyll *A*, *B* and phytochrome  $P_{R}$ ,  $P_{FR}$ .

Fig.1









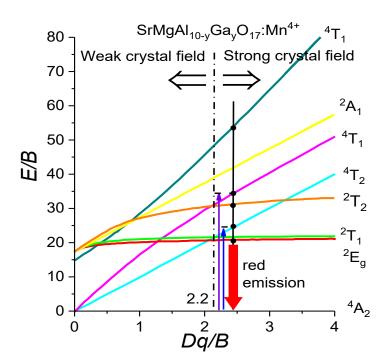


Fig.4

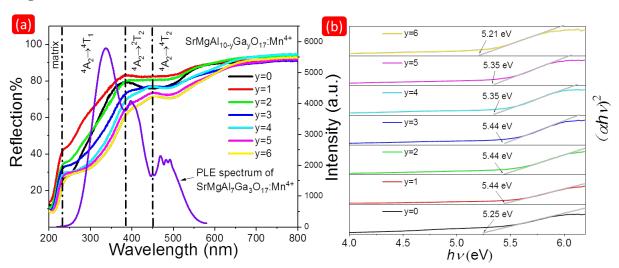


Fig.5

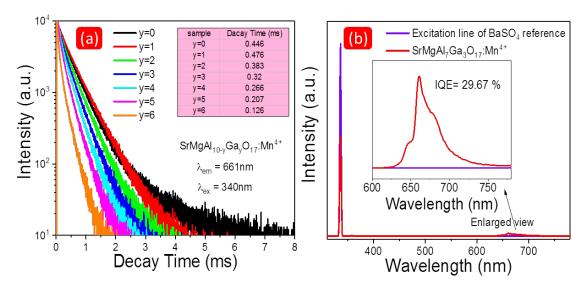


Fig.6

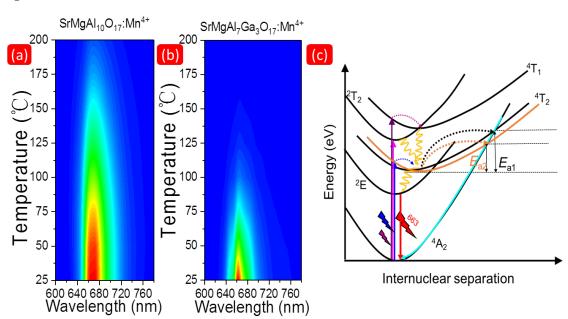
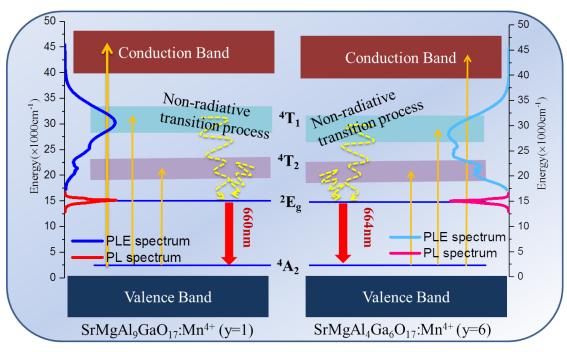


Fig.7





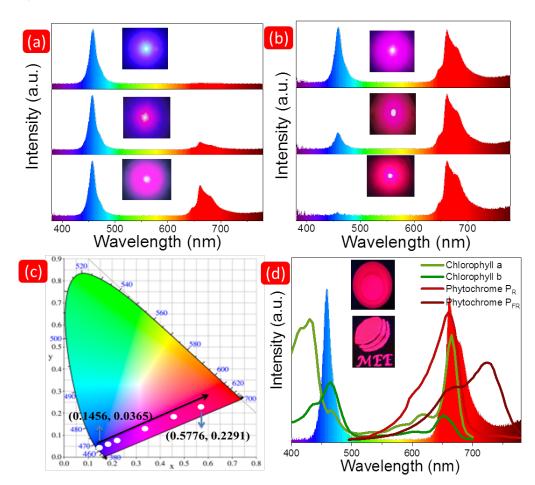


Fig.9